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APPLICANTS

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\*\* CONTINUING DATA \*\*\*\*\*

This application is a CON of 10/215,447 08/09/2002  
 which is a CIP of 09/928,124 08/10/2001 ABN  
 and is a CIP of 09/928,163 08/10/2001 ABN  
 and claims benefit of 60/381,320 05/16/2002

\*\* FOREIGN APPLICATIONS \*\*\*\*\*

UNITED STATES OF AMERICA PCT/US02/25289 08/09/2002

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Foreign Priority claimed 35 USC 119 (a-d) conditions met Verified and Acknowledged	<input type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> yes <input checked="" type="checkbox"/> no Allowance Examiner's Signature: <i>[Signature]</i> Initials: <i>SK</i>	STATE OR COUNTRY MN	SHEETS DRAWING 12	TOTAL CLAIMS 65	INDEPENDENT CLAIMS 6
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 25763  
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TITLE  
 Transistor having high dielectric constant gate insulating layer and source and drain forming schottky contact with substrate

☐ All Fees